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National Semiconductor

54FCT574 Octal D-Type Flip-Flop with TRI-STATE® Outputs

General Description

The 'FCT574 is an octal flip-flop with a buffered common Clock (CP) and a buffered common Output Enable ($\overline{\text{OE}}$). The information presented to the D inputs is stored in the flip-flops on the LOW-to-HIGH Clock (CP) transition.

The device is functionally identical to the 'FCT374 except for the pinouts.

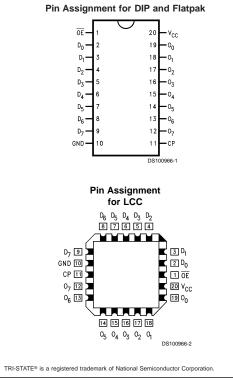
Features

- Inputs and outputs on opposite sides of package allowing easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to 'FCT374
- TRI-STATE outputs for bus-oriented applications
- Output sink capability of 32 mA, source capability of 12 mA
- TTL input and output level compatible
- CMOS power consumption
- Standard Microcircuit Drawing (SMD) 5962-8951301

Ordering Code

Military	Package Number	Package Description
54FCT574DMQB	J20A	20-Lead Ceramic Dual-In-Line
54FCT574FMQB	W20A	20-Lead Cerpack
54FCT574LMQB	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

Connection Diagrams



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Pin Descriptions

Pin	Description		
Names			
D ₀ -D ₇	Data Inputs		
D ₀ –D ₇ CP	Clock Pulse Input		
	(Active Rising Edge)		
ŌĒ	TRI-STATE Output Enable		
	Input (Active LOW)		
0 ₀ -0 ₇	TRI-STATE Outputs		

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Functional Description

The 'FCT574 consists of eight edge-triggered flip-flops with individual D-type inputs and TRI-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable (\overline{OE}) LOW, the contents of the eight flip-flops are available at the outputs. When \overline{OE} is HIGH, the outputs are in a high impedance state. Operation of the $\overline{\text{OE}}$ input does not affect the state of the flip-flops.

Function Table

	Inputs		Internal	Outputs	Function
OE	СР	D	Q	0	
Н	H or L	L	NC	Z	Hold

	Inputs		Inputs Internal Outputs		Function	
OE	СР	D	Q	0		
н	H or L	Н	NC	Z	Hold	
н	Ν	L	L	Z	Load	
н	Ν	Н	н	Z	Load	
L	Ν	L	L	L	Data Available	
L	Ν	Н	н	н	Data Available	
L	H or L	L	NC	NC	No Change in Data	
L	H or L	н	NC	NC	No Change in Data	

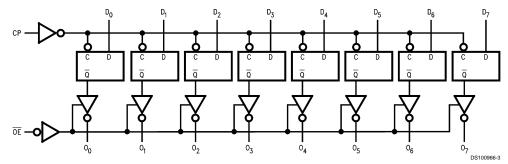
H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial

Z = High Impedance N = LOW-to-HIGH Transition

NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

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If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

–65°C to +150°C
-55°C to +125°C
–55°C to +175°C
-0.5V to +7.0V
-0.5V to +7.0V
-30 mA to +5.0 mA
-0.5V to 5.5V
–0.5V to $V_{\rm CC}$

Current Applied to Output in LOW State (Max) DC Latchup Source Current

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	-55°C to +125°C
Supply Voltage	
Military	+4.5V to +5.5V
Note 1: Absolute maximum ratings are value	es beyond which the device may

be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		FCT574		Units	V _{cc}	Conditions	
		Min Max	Max	1				
VIH	Input HIGH Voltage		2.0		V		Recognized HIGH Signal	
VIL	Input LOW Voltage			0.8	V		Recognized LOW Signal	
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	$I_{IN} = -18 \text{ mA}$	
V _{он}	Output HIGH	54FCT	4.3		V	Min	I _{OH} = -300 μA	
	Voltage	54FCT	2.4		V	Min	I _{он} = –12 mA	
V _{OL}	Output LOW Voltage	54FCT		0.2	V	Min	I _{OL} = 300 μA	
		54FCT		0.5	V	Min	I _{OL} = 32mA	
IIH	Input HIGH Current			5	μA	Max	V _{IN} = 2.7V (Note 3)	
				5			$V_{IN} = V_{CC}$	
I_{IL}	Input LOW Current			-5	μA	Max	V _{IN} = 0.5V (Note 3)	
				-5			$V_{IN} = 0.0V$	
I _{ozh}	Output Leakage Current			10	μA	0 – 5.5V	$V_{OUT} = 2.7V; \overline{OE} = 2.0V$	
l _{ozl}	Output Leakage Current			-10	μA	0 – 5.5V	$V_{OUT} = 0.5V; \overline{OE} = 2.0V$	
l _{os}	Output Short-Circuit Current		-60		mA	Max	$V_{OUT} = 0.0V$	
I _{CCQ}	Power Supply Current			1.5	mA	Max	$V_{IN} = 0.2V$ or $V_{IN} = 5.3V$, $f_I = 0MHz$	
ΔI_{CC}	Power Supply Current			2.0	mA	Max	V _{IN} = 3.4V	
I _{CCT}	Additional I _{CC} /Input			6.0	mA	Max	$ \begin{array}{l} V_{I} = V_{CC} - 2.1 V \text{ or } V_{IN} = GND, f_{CF} \\ = 10MHz, \text{ Outputs open, } \overline{OE} = \\ GND, \text{ one bit toggling at } f_{I} = 5MHz \\ 50\% \text{ duty cycle} \end{array} $	
				5.5	mA	Max	$ \begin{array}{l} V_{I}=5.3V \text{ or } V_{CC}=0.2V, \ f_{CP}=\\ 10MHz, \ Outputs \ open, \ \overline{OE}=GND,\\ one \ bit \ toggling \ at \ f_{I}=5MHz, \ 50\%\\ duty \ cycle \end{array} $	
I _{CCD}	Dynamic I _{CC} No Load			0.40	mA/ MHz	Max	Outputs Open, \overline{OE} = GND, One bit toggling, 50% duty cycle, V _{IN} = 5.3V or V _{IN} = 0.2V	

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54FCT574

twice the rated I_{OL} (mA)

-500 mA

54FCT574

AC Electrical Characteristics

Symbol	54FCT T _A = -55°C to +125°C Parameter V _{CC} = 4.5V to 5.5V C _L = 50 pF		Units	Fig. No.	
		Min	Мах	7	
t _{PLH}	Propagation Delay	2.0	11.0	ns	Figure 4
t _{PHL}	CP to O _n	2.0	11.0		
t _{PZH}	Output Enable Time	1.5	14.0	ns	Figure 6
t _{PZL}		1.5	14.0		
t _{PHZ}	Output Disable Time	1.5	8.0	ns	Figure 6
t _{PLZ}		1.5	8.0		

AC Operating Requirements

Symbol	bl Parameter $T_A = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = 4.5V \text{ to } 5.5V$ $C_L = 50 \text{ pF}$		$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = 4.5V \text{ to } 5.5V$ Units		Fig. No.	
		Min	Max			
t _s (H)	Setup Time, HIGH	3.5		ns	Figure 7	
t _s (L)	or LOW D _n to CP	3.5				
t _h (H)	Hold Time, HIGH	2.0		ns	Figure 7	
t _h (L)	or LOW D _n to CP	2.0				
t _w (H)	Pulse Width, CP,	7.0		ns	Figure 5	
t _w (L)	HIGH or LOW	7.0				

Capacitance

Symbol	Parameter	Тур	Units	Conditions T _A = 25°C
C _{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C _{OUT} (Note 4)	Output Capacitance	9.0	pF	$V_{\rm CC} = 5.0 V$

Note 4: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

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